









CEN2315

-30V ▲ 40mΩ ▲ -4A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type
P-channel enhancement mode
UL94V-0 rated flame retardant epoxy
SOT23T package ▲ MSL 3
Super high dense cell density for extremely low R_{DS(ON)}
Rugged and reliable

MAXIMUM RATINGS

| Parameter (T _A = 25°C, unless otherwise noted) | Characteristics | |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage | V _{DS} | -30V |
| Gate-Source Voltage | V _{GS} | -25V / + 20V |
| Continuous Drain Current | I _D | -4A |
| Pulsed Drain Current Note 1 | I _{DM} | -16A |
| Maximum Power Dissipation | P _D | 1.25W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55°C to +150°C |

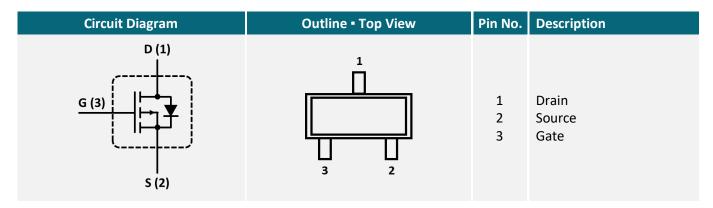
THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|--|--------------------|---------|
| Thermal Resistance, Junction-to-Ambient Note 2 | R _{TH_JA} | 100°C/W |

APPLICATIONS

| DC/DC | DC | Load | Power | USB |
|-----------|-----|----------|-------|---------|
| Converter | Fan | Switches | Banks | Storage |
| | | | 4 | Ŷ |

PIN DESCRIPTION





ELECTRICAL CHARACTERISTICS ▲ T_A = 25°C, unless otherwise noted

| ltem | Condition | Symbol | Min. | Тур. | Max. | Unit |
|--|---|---------------------|------|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V$, $I_D = -250\mu A$ | BV_{DSS} | -30 | | | V |
| Zero Gate Voltage Drain Current | V_{DS} = -30V, V_{GS} = 0V | I _{DSS} | | | -1 | μΑ |
| Gate Body Leakage Current, Forward | $V_{GS} = 20V, V_{DS} = 0V$ | I_{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | $V_{GS} = -25V$, $V_{DS} = 0V$ | I_{GSSR} | | | -100 | nA |
| On Characteristics Note 3 | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = -250 \mu A$ | $V_{GS(th)}$ | -1 | | -3 | V |
| Static Drain-Source On-Resistance | $V_{GS} = -10V$, $I_D = -3.8A$ | R _{DS(ON)} | | 40 | 50 | mΩ |
| Static Drain-Source On-Resistance | $V_{GS} = -4.5V$, $I_{D} = -3A$ | R _{DS(ON)} | | 60 | 85 | mΩ |
| Dynamic Characteristics Note 4 | | | | | | |
| Input Capacitance | $V_{DS} = -15V$, $V_{GS} = 0V$, $f = 1MHz$ | C _{ISS} | | 650 | | pF |
| Output Capacitance | $V_{DS} = -15V$, $V_{GS} = 0V$, $f = 1MHz$ | Coss | | 130 | | pF |
| Reverse Transfer Capacitance | $V_{DS} = -15V$, $V_{GS} = 0V$, $f = 1MHz$ | C_{RSS} | | 75 | | pF |
| Switching Characteristics Note 4 | | | | | | |
| Turn-On Delay Time | V_{DD} = -15V, V_{GS} = -10V, I_{D} = -1A, $R_{G(ext)}$ = 6Ω | $t_{\text{D(ON)}}$ | | 10 | | ns |
| Turn-On Rise Time | V_{DD} = -15V, V_{GS} = -10V, I_D = -1A, $R_{G(ext)}$ = 6Ω | t_{R} | | 4 | | ns |
| Turn-Off Delay Time | V_{DD} = -15V, V_{GS} = -10V, I_{D} = -1A, $R_{G(ext)}$ = 6Ω | $t_{\text{D(OFF)}}$ | | 36 | | ns |
| Turn-Off Fall Time | V_{DD} = -15V, V_{GS} = -10V, I_D = -1A, $R_{G(ext)}$ = 6Ω | t _F | | 6 | | ns |
| Total Gate Charge | V_{DS} = -15V, V_{GS} = -10V, I_D = -3.6A | Q_{G} | | 11.2 | | nC |
| Gate Source Charge | V_{DS} = -15V, V_{GS} = -10V, I_{D} = -3.6A | Q_{GS} | | 1.7 | | nC |
| Gate Drain Charge | $V_{DS} = -15V$, $V_{GS} = -10V$, $I_{D} = -3.6A$ | Q_{GD} | | 2 | | nC |
| Drain-Source Diode Characteristics an | nd Maximum Ratings | | | | | |
| Drain-Source Diode Forward Current Note 2 | | Is | | | -1 | Α |
| Drain-Source Diode Forward Voltage Note3 | $V_{GS} = 0V$, $I_S = -1A$ | V_{SD} | | | -1.2 | V |

Notes

1: Repetitive Rating: Pulse width limited by maximum junction temperature

2: Surface Mounted on FR4 Board, t ≤ 5 sec

3: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

4: Guaranteed by design, not subject to production testing.



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

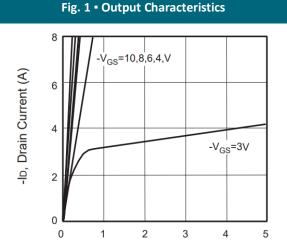


Fig. 2 • Transfer Characteristics

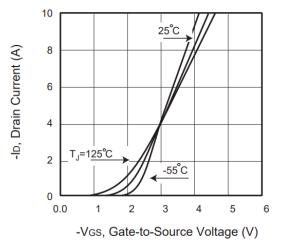


Fig. 3 • Capacitance

-VDS, Drain-to-Source Voltage (V)

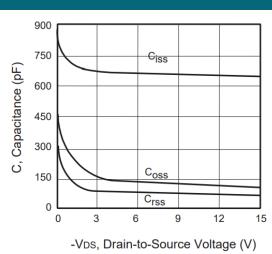


Fig. 4 • On-Resistance Variation with Temperature

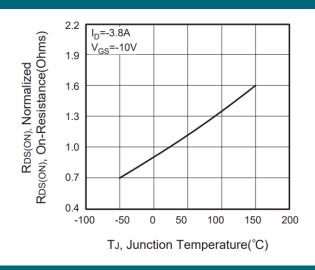


Fig. 5 • Gate Threshold Variation with Temperature

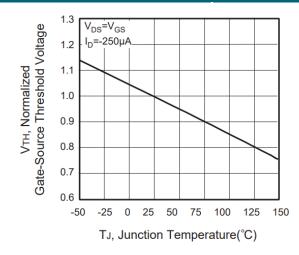
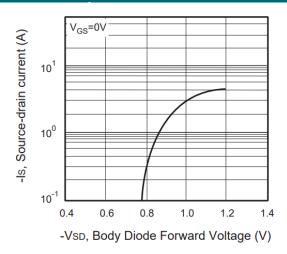


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



MGT

Manufacturer Group of Technology



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

Fig. 7 • Gate Charge

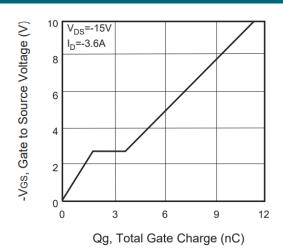


Fig. 8 • Maximum Safe Operating Area

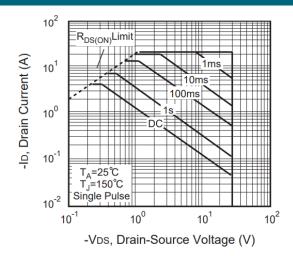
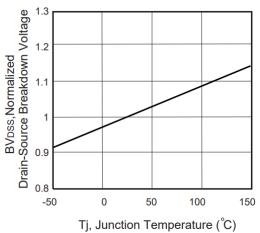


Fig. 9 • Breakdown Voltage Variation vs. Temperature





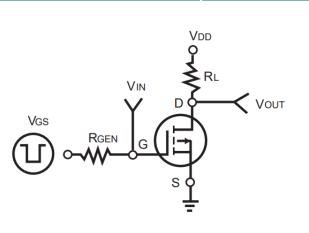
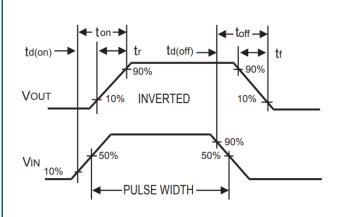


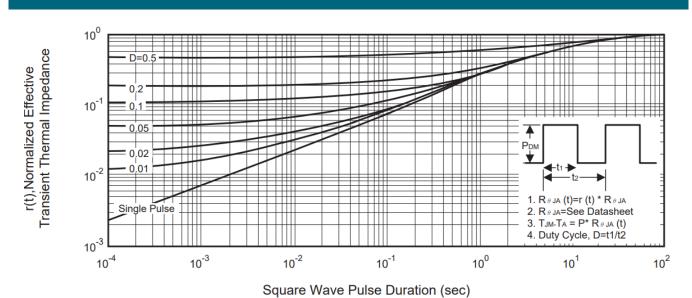
Fig. 11 • Switching Waveforms



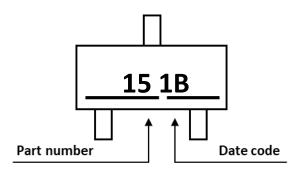


REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

Fig. 12 - Normalized Thermal Transient Impedance Curve

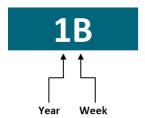


PART MARKING

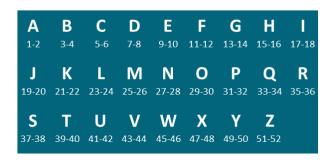


DATE CODE

Example: 1B



Coding list for "Week"

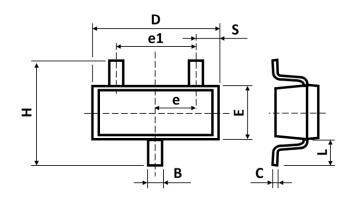


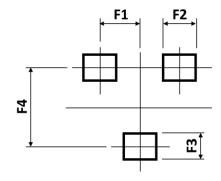
Coding list for "Year"

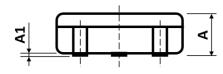




PACKAGE OUTLINE AND RECOMMENDED PAD LAYOUT







| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|-----------------------|--------------------|
| Α | 0.950 | - | 1.100 |
| A1 | 0.000 | - | 0.100 |
| В | 0.370 | - | 0.430 |
| С | 0.085 | - | 0.200 |
| D | 2.850 | - | 2.950 |
| E | 1.250 | - | 1.350 |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| e | 0.900 | - | 1.000 |
| e1 | 1.850 | - | 1.950 |
| Н | 2.350 | - | 2.450 |
| L | 0.500 | - | 0.600 |
| S | 0.410 | - | 0.610 |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | |
|-----|-----------------------|--------------------|--------------------|--|
| F1 | - | 0.950 | - | |
| F2 | - | 0.760 | - | |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| F3 | - | 0.760 | - |
| F4 | - | 2.290 | - |

Notes: 1. The suggested land pattern dimensions have been provided for reference only.

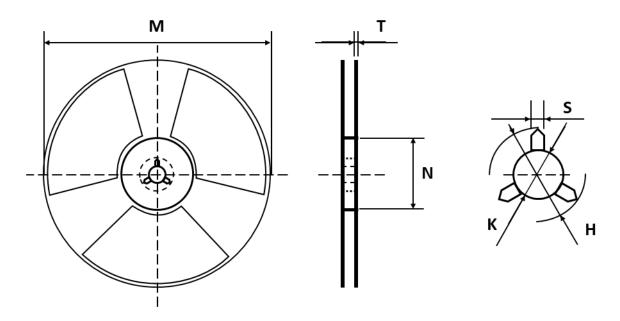
2. For further information, please reference document IPC-7351A.

ORDERING INFORMATION

| Part Number | Package | Packing | Reel Qty. | Inner Box Qty. |
|-------------|---------|---------|-----------|----------------|
| CEN2315 | SOT23T | 7" Reel | 3,000pcs | 15,000pcs |

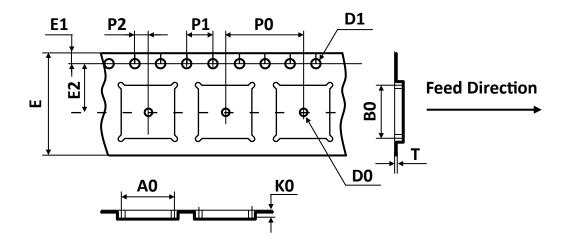


REEL DIMENSIONS ▲ All dimensions in mm



| Tape Size | Reel Size | M | N | Т | Н | K | S |
|-----------------|-----------|---------|--------|-------|-------|-------|-------|
| Q _{mm} | Ø180 | Ø178.00 | Ø54.00 | 1.20 | 20.00 | 13.30 | 3.00 |
| 8mm | ATOU | ±1.00 | ±0.50 | ±0.20 | ±1.00 | ±0.30 | ±1.00 |

TAPE DIMENSIONS ▲ All dimensions in mm

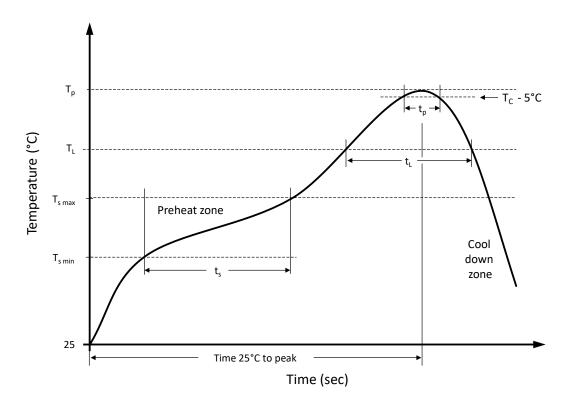


| Package | Α0 | В0 | КО | D0 | D1 | E | E1 | E2 | Р0 | P1 | P2 | T |
|---------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| SOT23T | 3.25 | 2.80 | 1.22 | 1.00 | 1.50 | 8.00 | 1.75 | 3.50 | 4.00 | 4.00 | 2.00 | 0.20 |
| 301231 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.05 | ±0.02 |

Note: All dimensions meet EIA-481-D requirements.



RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ **Refer to JEDEC J-STD-020E**

| Profile Features | | Sn-Pb Eutetic Assembly | Pb-Free Assembly |
|---|--------------------|------------------------|------------------|
| Preheat temperature min. | $T_{s min}$ | 100 °C | 150 °C |
| Preheat temperature max. | T _{s max} | 150 °C | 200 °C |
| Preheat time t _s from T _{s min} to T _{s max} | ts | 120 seconds | 120 seconds |
| Ramp-up rate (T₁ to Tp) | | max. 3 °C/second | max. 3 °C/second |
| Liquidous temperature | T_L | 183 °C | 217 °C |
| Time t _L maintained above T _L | t _L | 150 seconds max. | 150 seconds max. |
| Peak package body temperature | Tp | 235°C | 260°C |
| Timeframe of within 5°C below and up to max actual peak body temperature | t _p | 20 seconds max. | 30 seconds max. |
| Ramp-down rate (T _L to T _p) | | max. 6 °C/second | max. 6 °C/second |
| Time 25°C to peak temperature | | max. 6 minutes | max. 8 minutes |



REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
| | | | |
| | | | |
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| | | | |
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